Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!

Contact us

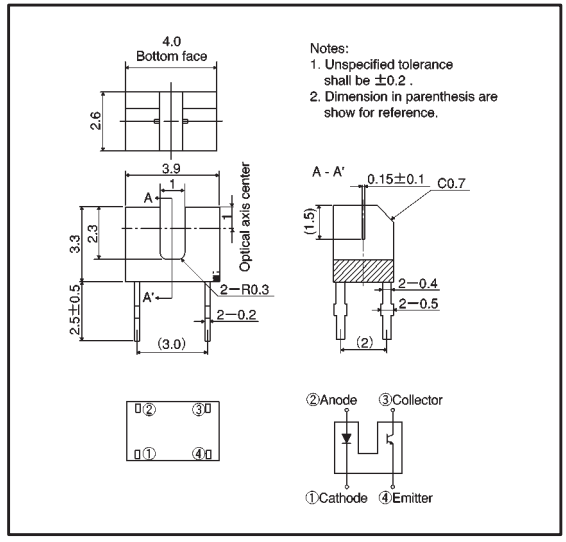
Tel: +86-755-8981 8866 Fax: +86-755-8427 6832
Email & Skype: info@chipsmall.com Web: www.chipsmall.com
Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

Photo interrupter, double-layer mold type

RPI-124

The RPI-124 is an ultra-small size, double–layer mold photointerrupter.

●External dimensions (Units: mm)



●Applications
Optical control equipment
Cameras
Floppy disk drives

●Features
1) Ultra-small.
2) High-precision position detection (slit width = 0.15 mm).
3) Minimal influence from stray light.
4) Low collector-emitter saturation voltage.

●Absolute maximum ratings (Ta = 25°C)

	Parameter	Symbol	Limits	Unit
Input(LED)	Forward current	I_F	50	mA
	Reverse voltage	V_R	5	V
	Power dissipation	P_D	80	mW
Output (photo-transistor)	Collector-emitter voltage	V_{CEO}	30	V
	Emitter-collector voltage	V_{ECO}	4.5	V
	Collector current	I_C	30	mA
	Collector power dissipation	P_C	80	mW
Operating temperature		Topr	−25～+85	℃
Storage temperature		Tstg	−30～+100	℃

●Electrical and optical characteristics (Ta = 25°C)

	Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input characteristics	Forward voltage	V_F	—	1.3	1.6	V	I_F=50mA
	Reverse current	I_R	—	—	10	μA	V_R=5V
Output characteristics	Dark current	I_{CEO}	—	—	0.5	μA	V_{CE}=10V
	Peak sensitivity wavelength	λ_P	—	800	—	nm	—
Transfer characteristics	Collector current	I_C	0.3	—	1.5	mA	V_{CC}=5V, I_F=20mA
	Collector-emitter saturation voltage	$V_{CE(sat)}$	—	—	0.3	V	I_F=20mA, I_C=0.15mA
	Response time	tr・tf	—	10	—	μs	V_{CC}=5V, I_F=20mA, R_L=100Ω

●Electrical and optical characteristic curves

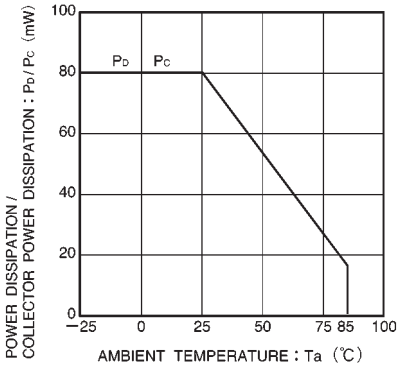


Fig.1 Power dissipation / collector power dissipation vs. ambient temperature

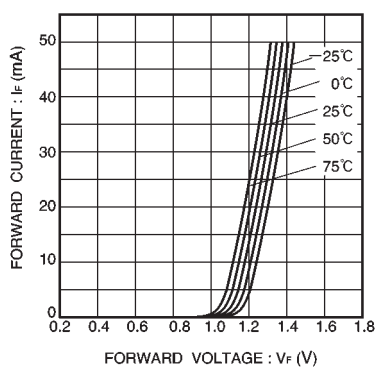


Fig.2 Forward current vs. forward voltage

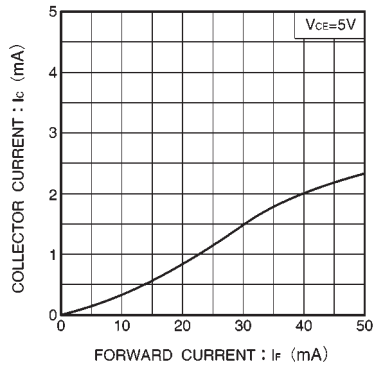


Fig.3 Collector current vs. forward current

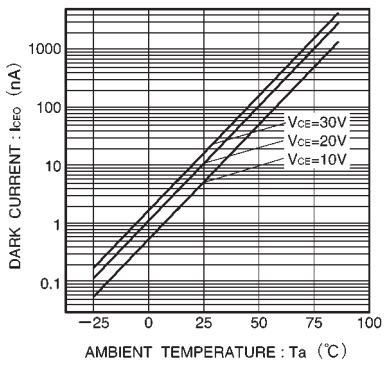


Fig.4 Dark current vs. ambient temperature

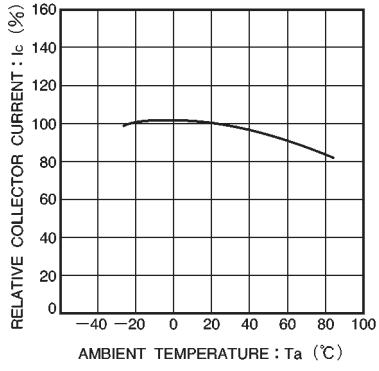


Fig.5 Relative output vs. ambient temperature

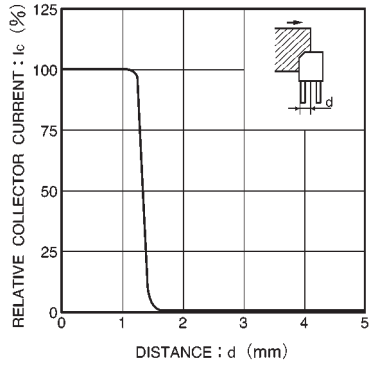


Fig.6 Relative output current vs. distance (I)

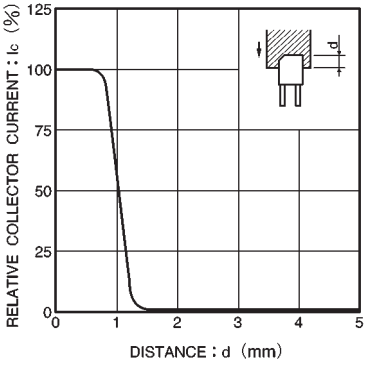


Fig.7 Relative output current vs. distance (II)

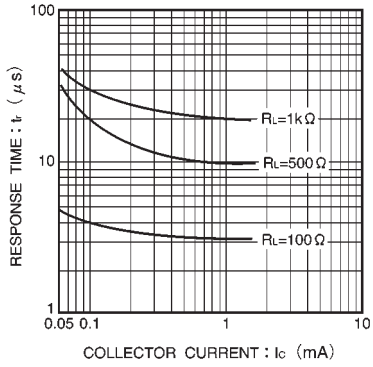


Fig.8 Response time vs. collector current

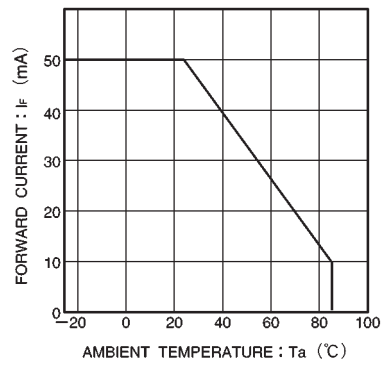


Fig.9 Forward current falloff

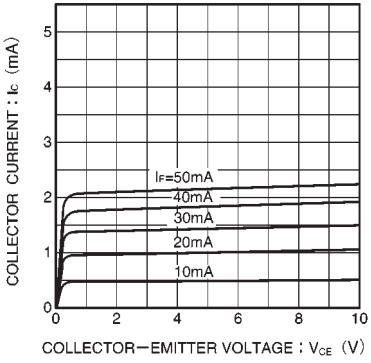
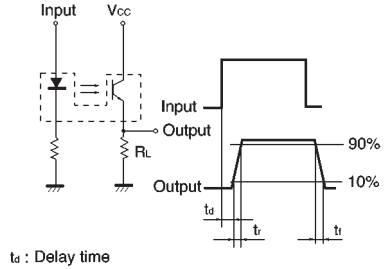


Fig.10 Output characteristics



td : Delay time
tr : Rise time (time for output current to rise from 10% to 90% of peak current)
tf : Fall time (time for output current to fall from 90% to 10% of peak current)

Fig.11 Response time mesurement circuit

Notes

- No technical content pages of this document may be reproduced in any form or transmitted by any means without prior permission of ROHM CO.,LTD.
- The contents described herein are subject to change without notice. The specifications for the product described in this document are for reference only. Upon actual use, therefore, please request that specifications to be separately delivered.
- Application circuit diagrams and circuit constants contained herein are shown as examples of standard use and operation. Please pay careful attention to the peripheral conditions when designing circuits and deciding upon circuit constants in the set.
- Any data, including, but not limited to application circuit diagrams information, described herein are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO.,LTD. disclaims any warranty that any use of such devices shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes no liability of whatsoever nature in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices, other than for buyer's right to use such devices itself, resell or otherwise dispose of the same, no express or implied right or license to practice or commercially exploit any intellectual property rights or other proprietary rights owned or controlled by
- ROHM CO., LTD. is granted to any such buyer.
- Products listed in this document use silicon as a basic material.
  Products listed in this document are no antiradiation design.

The products listed in this document are designed to be used with ordinary electronic equipment or devices (such as audio visual equipment, office-automation equipment, communications devices, electrical appliances and electronic toys).
Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

About Export Control Order in Japan

Products described herein are the objects of controlled goods in Annex 1 (Item 16) of Export Trade Control Order in Japan.
In case of export from Japan, please confirm if it applies to "objective" criteria or an "informed" (by MITI clause) on the basis of "catch all controls for Non-Proliferation of Weapons of Mass Destruction.